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X-ray detector

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The invention relates to a detector for an imaging device, such as in particular an X-ray device.

Dynamic flat panel X-ray detectors (FDXD) are increasingly being used in the field of medical diagnostics as universal detector components that can be used in different application-specific X-ray apparatuses. They comprise an array of sensor elements (sensor matrix), each sensor element of the said array comprising an element for charge collection, for example, a photodiode or a capacitor, and at least one readout element, for example a thin-film transistor, for forwarding the collected charges to an evaluation circuit. Flat panel X-ray detectors are typically produced from amorphous silicon (a-Si:H), but could comprise crystalline silicon, which enables more complex and higher-capacity components to be realized.

Contacting of a large-area detector of the above-described kind is generally

effected by means of so-called flex connections, that is to say, plastics foils with fine
conductor paths, or by way of wire-bond connections. Because of the small line and column
spacing of typically 50 to 250 μm and the large area of a sensor array, often several thousand
connections have to be produced between the sensor matrix and downstream evaluating
electronics. For detectors made of crystalline silicon, it is furthermore known that attempts

have been made to integrate at least some of the evaluating electronics directly into the wafer
that comprises the sensor matrix.

In addition, from US 5 914 485 it is known in the case of a detector having an array of sensor elements to mount integrated electronic modules (ICs) for the addressing at one edge of the substrate and to mount integrated electronic modules for a multiplexing of the signals read out from the sensor elements at another edge.

Against this background, it was an object of the present invention to make available a detector with improved signal properties that is cost-efficient to manufacture.

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That object is achieved by a detector having the features of claim 1 and by an imaging device having the features of claim 10. Advantageous embodiments are comprised in the subsidiary claims.

The inventive detector of an imaging device such as an X-ray arrangement or an optical imager comprises the following components:

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- a) A substrate, in which electronic circuits can be constructed. Typically, at least the regions of the substrate that comprise the electronics comprise amorphous or preferably crystalline silicon. Furthermore, the substrate can be applied to a mechanical support such as a glass plate, for example, or can comprise such a support.
- b) An array of sensor elements, which are constructed on one side of the substrate. Typically, the sensor elements are here arranged in a regular pattern, for example, hexagonally or grid-form in lines and columns. The sensor elements are preferably sensitive to X-radiation and/or to visible light, producing an electrical signal corresponding to the amount of radiation absorbed.
- 15 c) At least one integrated electronic module (IC) for processing sensor signals, which is mounted, that is to say, is mechanically fixed, at one edge of the substrate.

 Typically, the electronic module is located on the same side of the substrate as the array of sensor elements. Furthermore, the electronic module is connected at its electrical input side by way of signal leads to the sensor elements, and it comprises at least one analog-digital converter for conversion of the analog input signals present on the signal leads into digital output signals. These digital output signals can then be passed by way of readout leads from the detector to further external evaluating circuits.

The detector has the advantage that it is possible for an analog-digital conversion of the signals of the sensor elements to take place directly at the edge of the array of sensor elements, thereby avoiding signal interference and noise caused by long external leads. Further advantages result from the fact that at least one separate integrated module that is fixedly connected to the substrate is provided. By this means, on the one hand a mechanically robust design is achieved, and on the other hand self-comprised manufacture and optimization both of the array of sensor elements and of the integrated module are rendered possible by the modular construction. Through a separate yield maximization and through separate tests for the integrated module, a higher overall yield and a reduction in costs can be achieved in manufacture.

In a preferred construction of the detector, the substrate comprises amplifiers for amplifying the sensor signals before these enter the integrated module as input signals. In

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this way, signal losses en route from the sensor elements to the integrated module are reduced, which is to the benefit of the signal quality. The electronics of the substrate are in this case advantageously realized by crystalline silicon.

Furthermore, the substrate can comprise analog multiplexers, which are connected upstream of the integrated module in order to reduce its input signals, and/or the substrate can comprise digital multiplexers, which are connected downstream of the integrated module to reduce the output signals of the detector.

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According to another aspect of the detector, the integrated module comprises at least one amplifier for (pre)-amplification of the signals coming from the sensor elements. Furthermore, the integrated module can optionally comprise at least one multiplexer, by means of which a large number of input signals can be distributed in respect of time to a relatively small number of output lines. The integration of such a multiplexer therefore enables the number of external connections of the detector to be reduced.

The integrated module can comprise in particular crystalline silicon, which enables high-capacity circuits to be realized. Since the module is comparatively small in relation to the substrate of the detector, the use of crystalline silicon presents no problem. Moreover, the integrated module can be especially a CMOS circuit.

According to a preferred embodiment of the detector, the array of sensor elements extends at three sides of the substrate right to the edge. This means that only the side on which the at least one integrated module is located is not covered with the array of sensor elements. Such a construction of the detector extending in three directions with no edge strip enables a plurality of such detectors to be joined seamlessly to one another in order in this way to create larger detector areas. So that no edge of the substrate has to be used to accommodate an addressing circuit, the logic necessary for addressing the sensor elements is preferably integrated in the matrix of the sensor elements.

For the mechanical and electrical connection of the integrated module to the substrate, the methods of flip-chip contacting and wire-bonding or the mounting of "packaged ICs" (ICs in a housing) on a wafer are especially suitable.

The invention relates furthermore to an imaging device, which comprises a detector of the above-described kind. The imaging device can be in particular an X-ray arrangement, in which case the sensor elements of a directly converting detector are sensitive to X-radiation and of an indirectly converting detector are sensitive to scintillation light.

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These and other aspects of the invention are apparent from and will be elucidated, by way of non-limitative example, with reference to the embodiment(s) described hereinafter.

In the drawings:

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The Figure shows a view of a detector according to the invention.

The detector, shown schematically, can be in particular an optical imager or a dynamic flat panel X-ray detector (FDXD), or a module thereof. The detector comprises a rectangular, flat substrate 1, which comprises or comprises an electronic layer of amorphous or preferably crystalline silicon. The dimensions of the substrate 1 typically amount to 40 mm x 40 mm to 500 mm x 500 mm. On the top side of the substrate 1 visible in the Figure, there is a matrix or an array 2 of, for example, 2000 x 2000 sensor elements 3, the grid-form arrangement of which is indicated graphically. The array 2 extends in three directions as far as the edges of the substrate 1 at left, top and right in the Figure. The sensor elements 3 can comprise, for example, photodiodes and/or capacitors that accumulate electrical charges when irradiated with light or X-rays.

When a sensor element 3 is addressed by an addressing logic, not shown more specifically, distributed in the array 2, the charge signals of the sensor elements are applied line-wise to readout leads 6 running in the column direction. The readout leads 6 lead to the inputs of integrated electronic modules 4 (ICs), which are arranged at the free lower edge 5 of the substrate 1. The integrated modules 4 can comprise at least some of evaluating electronics, such as in particular amplifiers, analog-digital converters, multiplexers, interface-circuits and the like. Typically, a module 4 processes the signals of 50 to 500 signal leads 6. The size of the modules 4 can vary between a few square millimeters and a few square centimeters. The modules 4 preferably comprise crystalline silicon and are in the form of CMOS circuits.

The mechanical and electrical connection of the integrated modules 4 to the substrate 1 can be effected with a flip-chip technique (for example, ACF bonding, bump bonding or the like), with wire bonds or with packaged ICs (packaged ICs mounted on wafer). The connection of the integrated modules 4 to external evaluating electronics (not illustrated) is effected by means of flex connections 7.

In an especially preferred construction of the detector, the crystalline silicon electronics of the substrate 1 comprise amplifiers for amplifying the sensor signals. Here, a

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separate amplifier can be provided either for each individual sensor element 3 of the substrate or for each column lead 6. The integrated modules 4 then comprise primarily the analog-digital converters. The substrate 1 can furthermore additionally comprise analog multiplexers (connected upstream) and/or digital multiplexers (connected downstream).

Compared with detectors having evaluating electronics located completely outside the substrate, a detector of the above-described kind has the following advantages:

- The number of connections (for example, flex bonds) leaving the substrate 1 can be significantly reduced by multiplexers in the modules 4.
- A mechanically robust design is achieved.

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The evaluating electronics comprised in the modules 4 lie very close to the sensor elements 3, which leads to a higher signal quality owing to reduced noise.

Compared with detectors having evaluating electronics integrated in the substrate, the following advantages are achieved:

- Owing to the modular design, a self-comprised manufacture and optimization of the sensor matrix and integrated modules 4 is possible.
- By separate yield-maximization and by separate tests of the modules 4, a production of the detectors with an overall higher yield and therefore at lower cost is possible.

A further advantage of the detector lies in the fact that the array of sensor

elements 3 extends at three sides right to the outermost edge of the substrate 1. It is therefore
possible to combine several detectors of this kind as it were seamlessly to form a larger
detector area.